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DATA SHEET www.onsemi.com

Digital Transistors (BRT) R1 = 1 k\Omega, R2 = 1 k\Omega

NPN Transistors with Monolithic Bias Resistor Network

MUN2230, MMUN2230L, MUN5230, DTC113EE, DTC113EM3, NSBC113EF3

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

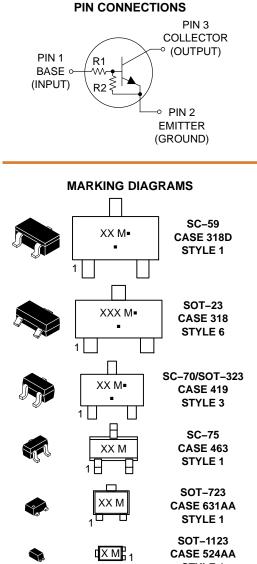
Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM	RATINGS	(T₄ = 25°C)
		$(1_{A} - 20 0)$

Rating	Symbol	Max	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current – Continuous	۱ _C	100	mAdc
Input Forward Voltage	V _{IN(fwd)}	10	Vdc
Input Reverse Voltage	V _{IN(rev)}	10	Vdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



 XXX
 =
 Specific Device Code

 M
 =
 Date Code*

 •
 =
 Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet. NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping [†]
SMUN2230T1G*	8G	SC–59 (Pb–Free)	3000 / Tape & Reel
MMUN2230LT1G, NSVMMUN2230LT1G*	A8G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5230T1G	8G	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC113EET1G	7Q	SC-75 (Pb-Free)	3000 / Tape & Reel
DTC113EM3T5G, NSVDTC113EM3T5G*	7A	SOT-723 (Pb-Free)	8000 / Tape & Reel

DISCONTINUED (Note 1)

MUN2230T1G	8G	SC–59 (Pb–Free)	3000 / Tape & Reel
NSBC113EF3T5G	D (180°)**	SOT–1123 (Pb–Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

** $(xx^{\circ}) = Degree rotation in the clockwise direction.$

1. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

(1) SC-75 and SC-70/SOT323; Minimum Pad

(4) SOT-1123; 100 mm², 1 oz. copper trace

(2) SC-59; Minimum Pad

(3) SOT-23; Minimum Pad

(5) SOT-723; Minimum Pad

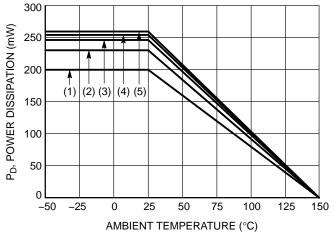


Figure 1. Derating Curve

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2230)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	PD	230 338 1.8 2.7	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	540 370	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ ext{ heta}JL}$	264 287	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-23) (MMUN2230L)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	P _D	246 400 2.0 3.2	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 3)	R_{\thetaJA}	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ extsf{ heta}JL}$	174 208	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5230)	-		-	
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	PD	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ ext{ heta}JL}$	280 332	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTC113EE)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	P _D	200 300 1.6 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	600 400	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-723) (DTC113EM3)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	P _D	260 600	mW
Derate above 25°C 2. FR-4 @ Minimum Pad.	(Note 2) (Note 3)		2.0 4.8	mW/°C

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit		
THERMAL CHARACTERISTICS (SOT-723) (DTC113EM3)						
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	R_{\thetaJA}	480 205	°C/W		
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C		
THERMAL CHARACTERISTICS (SOT-1123) (NSBC113EF3)						
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 4) (Note 5) (Note 4) (Note 5)	P _D	254 297 2.0 2.4	mW mW/°C		
Thermal Resistance, Junction to Ambient	(Note 4) (Note 5)	R_{\thetaJA}	493 421	°C/W		
Thermal Resistance, Junction to Lead	(Note 4)	$R_{\theta JL}$	193	°C/W		
Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C		

2. FR-4 @ Minimum Pad.

3. FR-4 @ 1.0 x 1.0 Inch Pad.

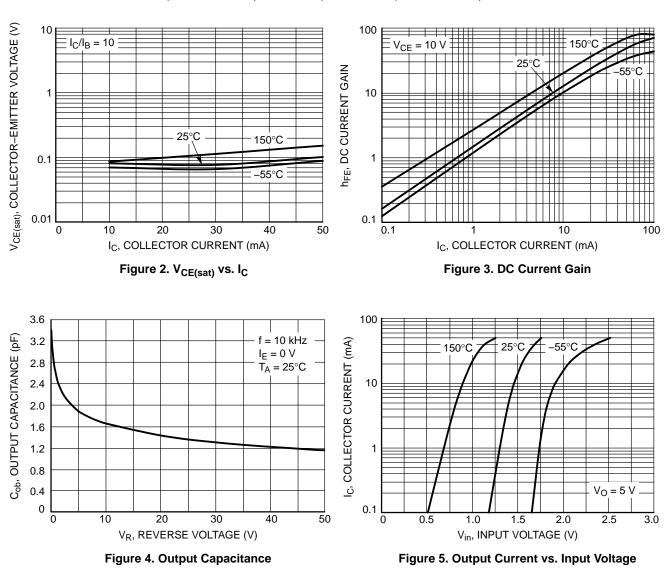
FR-4 @ 100 mm², 1 oz. copper traces, still air.
 FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 3. ELECTRICAL CHARACTERISTICS (T_A = 25° C, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			
Collector–Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$	I _{CBO}	_	_	100	nAdc
Collector-Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	I _{CEO}	_	_	500	nAdc
Emitter–Base Cutoff Current ($V_{EB} = 6.0 \text{ V}, I_C = 0$)	I _{EBO}	_	_	4.3	mAdc
Collector-Base Breakdown Voltage $(I_C = 10 \ \mu A, I_E = 0)$	V _(BR) CBO	50	_	-	Vdc
Collector–Emitter Breakdown Voltage (Note 6) $(I_{C} = 2.0 \text{ mA}, I_{B} = 0)$	V _(BR) CEO	50	-	-	Vdc
ON CHARACTERISTICS		•			
DC Current Gain (Note 6) ($I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$)	h _{FE}	3.0	5.0	-	
Collector–Emitter Saturation Voltage (Note 6) ($I_C = 10 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{CE(sat)}	_	_	0.25	Vdc
Input Voltage (off) ($V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A}$)	V _{i(off)}	_	1.2	0.5	Vdc
Input Voltage (on) ($V_{CE} = 0.3 \text{ V}, I_C = 20 \text{ mA}$)	V _{i(on)}	2	1.6	-	Vdc
Output Voltage (on) ($V_{CC} = 5.0 \text{ V}, \text{ V}_{B} = 2.5 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega$)	V _{OL}	_	_	0.2	Vdc
Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.05 V, R _L = 1.0 k Ω)	V _{OH}	4.9	_	_	Vdc
Input Resistor	R1	0.7	1.0	1.3	kΩ
Resistor Ratio	R ₁ /R ₂	0.8	1.0	1.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle \leq 2%.



TYPICAL CHARACTERISTICS MUN2230, MMUN2230L, MUN5230, DTC113EE, DTC113EM3, NSBC113EF3

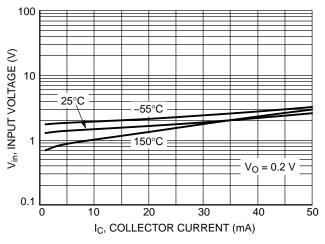
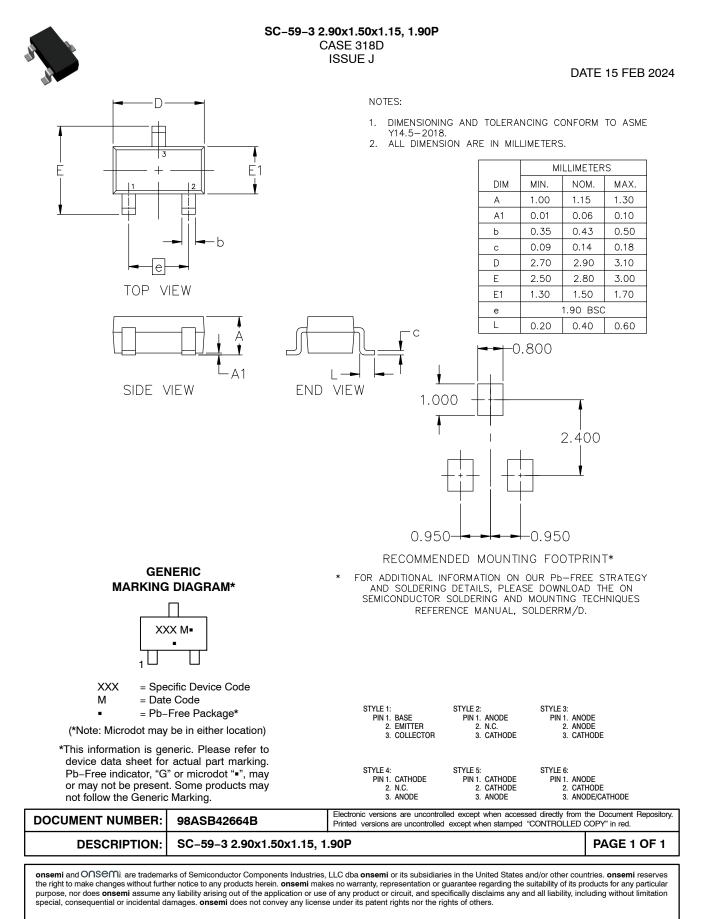


Figure 6. Input Voltage vs. Output Current

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024









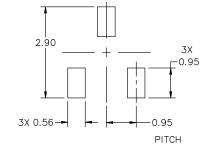




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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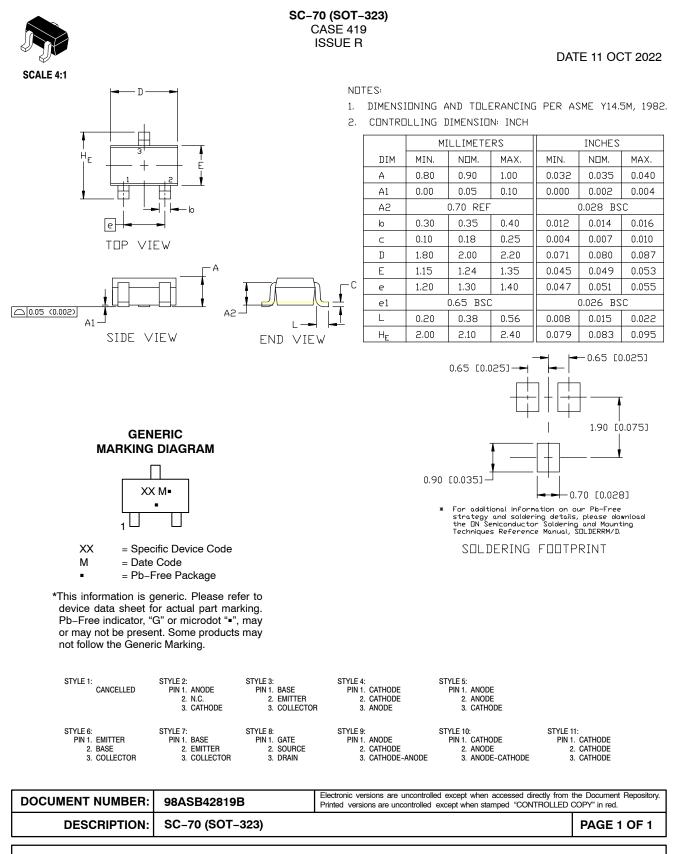
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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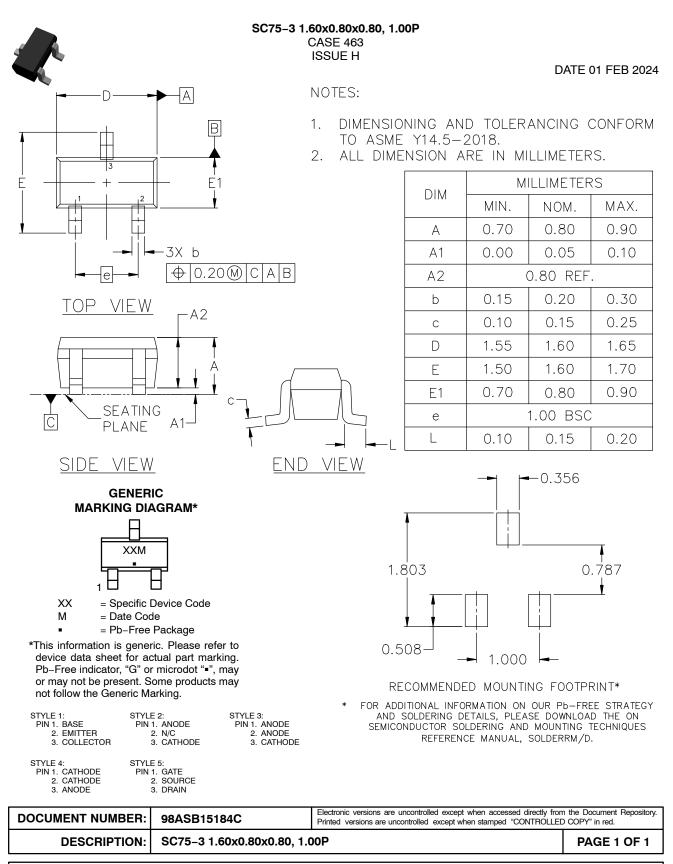
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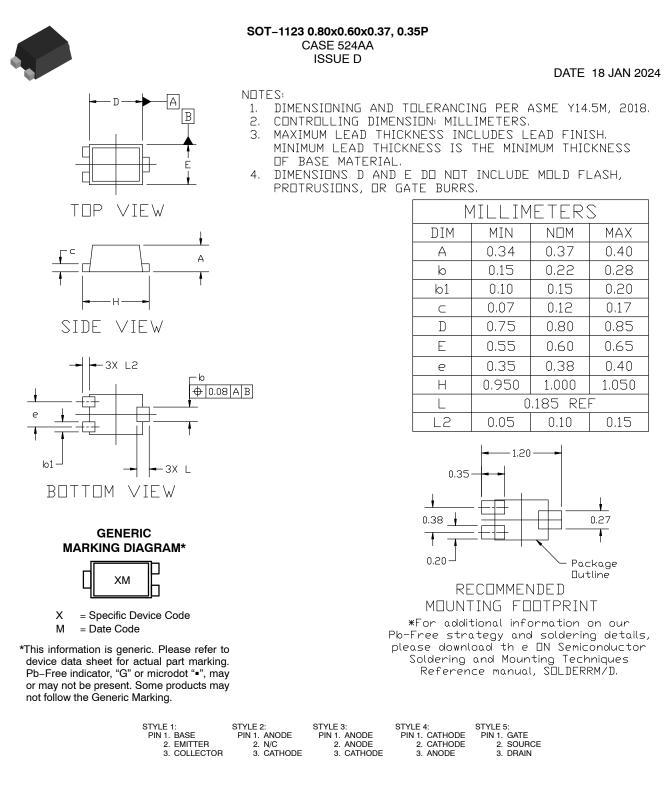
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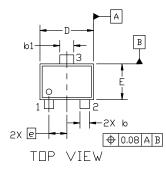


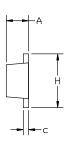
SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

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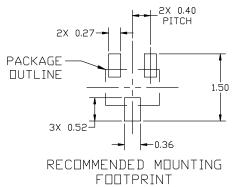
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- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



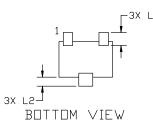


SIDE VIEW

		MILLIMETERS						
	DIM	MIN.	NDM.	MAX.				
1	А	0.45	0.50	0.55				
	b	0.15	0.21	0.27				
	b1	0.25	0.31	0.37				
	С	0.07	0.12	0.17				
	D	1.15	1.20	1.25				
	E	0.75	0.80	0.85				
	e	0.40 BSC						
	Н	1.15	1.20	1.25				
	L	0.29 REF						
	L2	0.15	0.20	0.25				



*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code = Date Code Μ

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 2. EMITTER		2. ANODE 2	4: . CATHODE . CATHODE . ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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